# 30mA Inverting Charge Pump in SOT23 for EMI-Sensitive Automotive Applications

#### **ABSOLUTE MAXIMUM RATINGS**

IN to GND	0.3V to +6V	
C1+, SHDN to GND	0.3V to (V <sub>IN</sub> +0.3V)	
C1- to GND	(V <sub>OUT</sub> - 0.3V) to +0.3V	
OUT to GND	+0.3V to -6V	
OUT Output Current	90mA	(
OUT Short Circuit to GND	Indefinite	
Continuous Power Dissipation ( $T_A = +7$	0°C)	5
6-Pin SOT23 (derate 7.4mW/°C above +7	70°C) (Note 1)595mW	L

Junction-to-Case Thermal Resistance (θ <sub>JC</sub> ) (No 6-Pin SOT23		39°C/W
Junction-to-Ambient Thermal Resistance (θJA)	(Note 1)	
6-Pin SOT23	1	34°C/W
Operating Temperature Range	40°C to -	+105°C
Junction Temperature		+150°C
Storage Temperature Range	65°C to -	+150°C
Lead Temperature	(	Note 2)

- **Note 1:** Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to <a href="https://www.maximintegrated.com/thermal-tutorial">www.maximintegrated.com/thermal-tutorial</a>.
- Note 2: This device is constructed using a unique set of packaging techniques that impose a limit on the thermal profile the device can be exposed to during board-level solder attach and rework. Maxim recommends the use of the solder profiles recommended in the industry-standard specification, JEDEC 020A, paragraph 7.6, Table 3 for IR/VPR and Convection reflow processes. Preheating, per this standard, is required. Hand or wave soldering is not recommended.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **ELECTRICAL CHARACTERISTICS**

(Circuit of Figure 1, C1 = C2 =  $2.2\mu$ F,  $V_{IN} = V_{\overline{SHDN}} = +5V$ ,  $V_{GND} = 0$ ,  $T_A = 0^{\circ}C$  to  $+105^{\circ}C$ , unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .)

PARAMETER	CONDI	TIONS	MIN	TYP	MAX	UNITS
Cupply Voltage Denge	D. EleO	T <sub>A</sub> = +25°C	1.4		5.5	V
Supply Voltage Range	$R_L = 5k\Omega$	$T_A = 0$ °C to $+105$ °C	1.5		5.5	
Quiescent Supply Current	$T_A = +25^{\circ}C \text{ (Note 3)}$			950	1700	μA
Shutdown Supply Current	V <del>ourni</del> - 0	T <sub>A</sub> = +25°C		0.002	1	
Shutdown Supply Current	VSHDN = 0	$T_A = 0$ °C to $+105$ °C		0.03		μΑ
Short-Circuit Current	Output shorted to grou	$_{INd}$ , $T_{A}$ = $+25^{\circ}C$		170		mA
Oscillator Frequency	T <sub>A</sub> = +25°C		70	125	180	kHz
Voltage Conversion Efficiency	I <sub>OUT</sub> = 0, T <sub>A</sub> = +25°C	I <sub>OUT</sub> = 0, T <sub>A</sub> = +25°C		99.9		%
Output Decistance	I <sub>OUT</sub> = 30mA (Note 4)	T <sub>A</sub> = +25°C		12	25	Ω
Output Resistance		$T_A = 0$ °C to $+105$ °C			36	
OUT-to-GND Shutdown Resistance	V <del>SHDN</del> = 0, OUT is interior in shutdown	VSHDN = 0, OUT is internally pulled to GND in shutdown		3	8.5	Ω
CUDA brook basis History	2.5V ≤ V <sub>IN</sub> ≤ 5.5V	$2.5 \text{V} \leq \text{V}_{\text{IN}} \leq 5.5 \text{V}$				
SHDN Input Logic-High	$V_{IN(MIN)} \le V_{IN} \le 2.5V$	$V_{IN(MIN)} \le V_{IN} \le 2.5V$				V
CHDN Input Logic Lour	$2.5V \le V_{\text{IN}} \le 5.5V$	$2.5V \le V_{\text{IN}} \le 5.5V$			0.6	V
SHDN Input Logic-Low	$V_{IN(MIN)} \le V_{IN} \le 2.5V$	$V_{IN(MIN)} \le V_{IN} \le 2.5V$			0.2	
SHDN Bias Current	SHDN = GND or IN	$T_A = +25^{\circ}C$	-100	+0.05	+100	nA
SI DIA DIAS GUITETIL	SHUN = GIND OF IIN	$T_A = 0$ °C to $+105$ °C		10		
Wake-Up Time from Shutdown	I <sub>OUT</sub> = 15mA	I <sub>OUT</sub> = 15mA		100		μs

# 30mA Inverting Charge Pump in SOT23 for EMI-Sensitive Automotive Applications

#### **ELECTRICAL CHARACTERISTICS (continued)**

(Circuit of Figure 1, C1 = C2 =2.2 $\mu$ F, V<sub>IN</sub> = V<sub>SHDN</sub> = +5V, V<sub>GND</sub> = 0, **T<sub>A</sub> = 0°C to +105°C**, unless otherwise noted. Typical values are at T<sub>A</sub> = +25°C.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
Supply Voltage Range	$R_L = 5k\Omega$	1.6		5.5	V	
Output Current	Continuous, long-term			60	mA <sub>RMS</sub>	
Quiescent Supply Current	(Note 3)			1800	μΑ	
Oscillator Frequency		60	125	200	kHz	
Output Resistance	I <sub>OUT</sub> = 30mA (Note 5)			36	Ω	
OUT-to-GND Shutdown Resistance	VSHDN = 0, OUT is internally pulled to GND in shutdown			8.5	Ω	
CLIDAL la sectada esta di tala	$2.5V \le V_{\text{IN}} \le 5.5V$	2.1			V	
SHDN Input Logic-High	$V_{IN(MIN)} \le V_{IN} \le 2.5V$	V <sub>IN</sub> - 0.2				
CLIDN Input Logic Low	$2.5 \text{V} \leq \text{V}_{\text{IN}} \leq 5.5 \text{V}$			0.6	- v	
SHDN Input Logic-Low	$V_{IN(MIN)} \le V_{IN} \le 2.5V$			0.2		

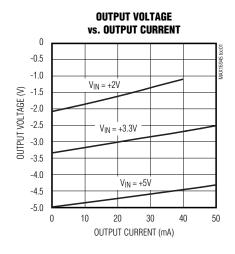
**Note 3:** The MAX16945 may draw high supply current during startup, up to the minimum operating supply voltage. To guarantee proper startup, the input supply must be capable of delivering 90mA more than the maximum load current.

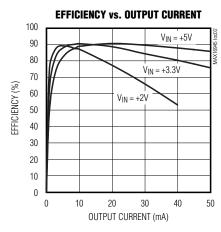
**Note 4:** Output resistance is guaranteed with capacitor ESR of  $0.3\Omega$  or less.

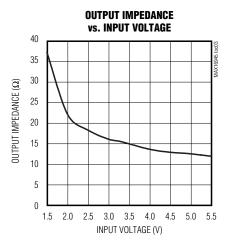
Note 5: All specifications from -40°C to +105°C are guaranteed by design, not production tested.

### Typical Operating Characteristics

(Circuit of Figure 1, C1 = C2 =  $2.2\mu F$ ,  $V_{IN} = V_{\overline{SHDN}} = +5V$ ,  $V_{GND} = 0$ ,  $T_A = +25$ °C, unless otherwise noted.)



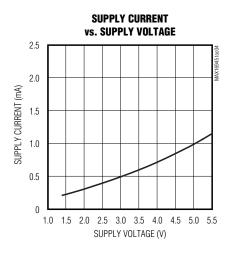


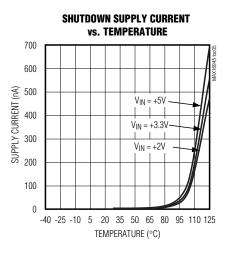


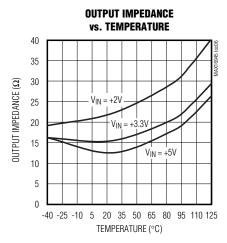
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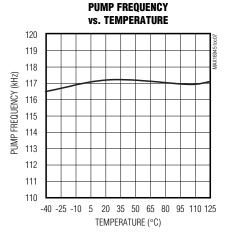
### Typical Operating Characteristics (continued)

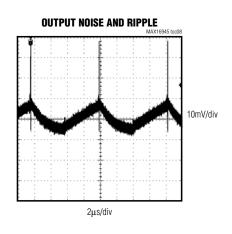
(Circuit of Figure 1, C1 = C2 = 2.2µF, V<sub>IN</sub> = V<sub>SHDN</sub> = +5V, V<sub>GND</sub> = 0, T<sub>A</sub> = +25°C, unless otherwise noted.)

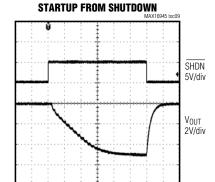












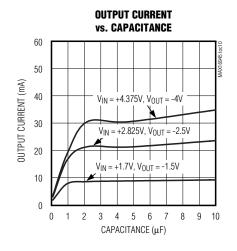
4 Maxim Integrated

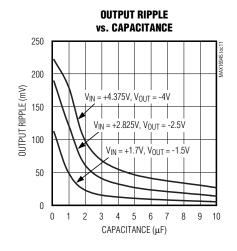
40µs/div

# 30mA Inverting Charge Pump in SOT23 for EMI-Sensitive Automotive Applications

### Typical Operating Characteristics (continued)

(Circuit of Figure 1, C1 = C2 = 2.2µF, V<sub>IN</sub> = V<sub>SHDN</sub> = +5V, V<sub>GND</sub> = 0, T<sub>A</sub> = +25°C, unless otherwise noted.)





### **Pin Description**

PIN	NAME	FUNCTION	
1	OUT	Inverting Charge-Pump Output	
2	IN	Power-Supply Voltage Input. Input range is 1.4V to 5.5V.	
3	C1-	Negative Terminal of the Flying Capacitor	
4	GND	Ground	
5	SHDN	Shutdown Input. Drive SHDN high for normal operation; drive SHDN low for shutdown mode. OUT is actively pulled to ground during shutdown.	
6 C1+ Positive Terminal of the Flying Capacitor			

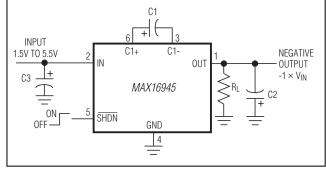


Figure 1. Typical Application Circuit

### **Detailed Description**

The MAX16945 capacitive charge pump inverts the voltage applied to its input. For highest performance, use low-ESR capacitors.

During the first half-cycle, switches S2 and S4 open, switches S1 and S3 close, and capacitor C1 charges to the voltage at IN (Figure 2). During the second half-cycle, S1 and S3 open, S2 and S4 close, and C1 is level shifted downward by  $V_{\mbox{\footnotesize{IN}}}$  volts. This connects C1 in parallel with the reservoir capacitor C2. If the voltage across C2 is smaller than the voltage across C1, charge flows from C1 to C2 until the voltage across C2 reaches -V\_{\mbox{\footnotesize{IN}}}. The absolute value of the inverting output

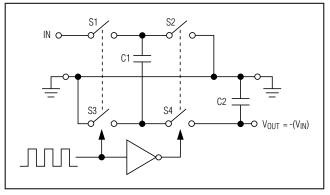


Figure 2. Ideal Voltage Inverter

voltage is always smaller than the value of the input voltage due to the losses of the flying capacitor C1 and the resistance of the switches S1–S4.

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#### **Efficiency Considerations**

The efficiency of the MAX16945 is dominated by its quiescent supply current (IQ) at low output current, and by its output impedance (ROUT) at higher output current. Efficiency is calculated as follows:

$$\eta \cong \frac{I_{OUT}}{I_{OUT} + I_{Q}} \left( 1 - \frac{I_{OUT} \times R_{OUT}}{V_{IN}} \right)$$

where the output impedance is roughly approximated by:

$$R_{OUT} \cong \frac{1}{\left(f_{OSC}\right) \times C1} + 2R_{SW} + 4ESR_{C1} + ESR_{C2}$$

The first term is the effective resistance of an ideal switched-capacitor circuit (Figures 3a and 3b), and Rsw is the sum of the charge pump's internal switch resistances (typically  $4\Omega$  to  $5\Omega$  at  $V_{IN}=+5V$ ). The typical output impedance is more accurately determined from the *Typical Operating Characteristics*.

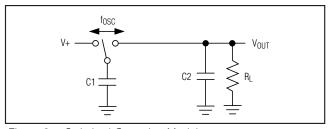


Figure 3a. Switched-Capacitor Model

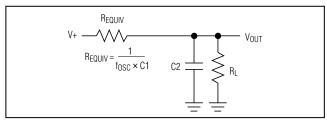


Figure 3b. Equivalent Circuit

#### **Current Limit**

The MAX16945 limits its input current upon startup to 170mA (typ). This prevents low-current or higher output impedance input supplies (such as alkaline cells) from being overloaded when power is applied or when the device awakes from shutdown.

#### Shutdown

The MAX16945 has a logic-controlled shutdown input. Driving  $\overline{SHDN}$  low places the device in a low-power shutdown mode. The charge-pump switching halts, supply current is reduced to 2nA, and OUT is actively pulled to ground through a  $3\Omega$  resistance.

Driving SHDN high will restart the charge pump. The switching frequency and capacitor values determine how soon the device will reach 90% of the input voltage.

### **Applications Information**

#### **Capacitor Selection**

The charge-pump output resistance is a function of the ESR of C1 and C2. To maintain the lowest output resistance, use capacitors with low ESR.

#### Flying Capacitor (C1)

Increasing the flying capacitor's value reduces the output resistance. Above a certain point, increasing C1's capacitance has negligible effect because the output resistance is then dominated by internal switch resistance and capacitor ESR.

#### Output Capacitor (C2)

Increasing the output capacitor's value reduces the output ripple voltage. Decreasing its ESR reduces both output resistance and ripple. Lower capacitance values can be used with light loads if higher output ripple can be tolerated. Use the following equation to calculate the peak-to-peak ripple:

$$V_{RIPPLE} = \frac{I_{OUT}}{2(f_{OSC})C2} + 2 \times I_{OUT} \times ESR_{C2}$$

#### Input Bypass Capacitor (C3)

If necessary, bypass the incoming supply to reduce its AC impedance and the impact of the MAX16945's switching noise. An input bypass capacitor (C3) with a value equal to that of C1 is recommended.

#### **Voltage Inverter**

The most common application for these devices is a charge-pump voltage inverter (Figure 1). This application requires only two external components, capacitors C1 and C2, plus an input bypass capacitor C3, if necessary. See the *Capacitor Selection* section for suggested capacitor sizes.

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#### **Cascading Devices**

Two devices can be cascaded to produce an even larger negative voltage (Figure 4). The unloaded output voltage is normally -2 x  $V_{\rm IN}$ , but this is reduced slightly by the output resistance of the first device when multiplied by the quiescent current of the second. When cascading more than two devices, the output resistance rises dramatically. The maximum load current and startup current of the nth cascaded circuit must not exceed the maximum output current capability of the (n-1)th circuit to ensure proper startup.

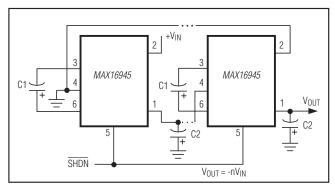


Figure 4. Cascading MAX16945s to Increase Output Voltage

#### **Paralleling Devices**

Paralleling multiple MAX16945s reduces the output resistance. Each device requires its own charge-pump capacitor (C1), but the reservoir capacitor (C2) serves all devices (Figure 5). Increase C2's value by a factor of n, where n is the number of parallel devices. Figure 5 shows the equation for calculating output resistance.

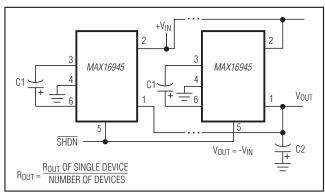


Figure 5. Paralleling MAX16945s to Reduce Output Resistance

#### **Combined Doubler/Inverter**

In the circuit of Figure 6, capacitors C1 and C2 form the inverter, while C3 and C4 form the doubler. C1 and C3 are the pump capacitors; C2 and C4 are the reservoir capacitors. Because both the inverter and doubler use part of the charge-pump circuit, loading either output causes both outputs to decline toward GND. Make sure the sum of the currents drawn from the two outputs does not exceed 30mA.

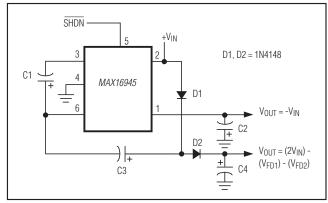


Figure 6. Combined Doubler and Inverter

# Heavy Load Connected to a Positive Supply

Under heavy loads, where a higher supply is sourcing current into OUT, the OUT supply must not be pulled above ground. Applications that sink heavy current into OUT require a Schottky diode (1N5817) between GND and OUT, with the anode connected to OUT (Figure 7).

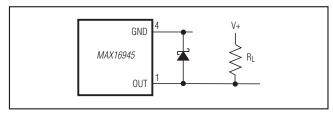


Figure 7. Heavy Load Connected to a Positive Supply

#### **Layout and Grounding**

Good layout is important, primarily for good noise performance. To ensure good layout, mount all components as close together as possible, keep traces short to minimize parasitic inductance and capacitance, and use a ground plane.

Process: BiCMOS

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**Chip Information** 

### Package Information

For the latest package outline information and land patterns (footprints), go to www.maximintegrated.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

	PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
Ī	6 SOT23	U6F+6	21-0058

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#### **Revision History**

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	8/08	Initial release	_
1	6/09	Updated Ordering Information	1
2	6/15	Updated package code Package Information	8



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